NSN 5962-01-379-9684

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-379-9684
Body Length:
Between 0.930 inches and 0.975 inches
Body Width:
Between 0.246 inches and 0.300 inches
Body Height:
0.200 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-55.0/+150.0 degrees celsius
End Application:
3757525 system: f16 dflcc
Features Provided:
Bipolar and high power and programmed and tested to mil-std-883 and 3-state output
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Metal oxide-semiconductor logic
Voltage Rating And Type Per Characteristic:
5.5 volts absolute input and 7.0 volts applied
Memory Device Type:
Rom
Hybrid Technology Type:
Monolithic
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
20 printed circuit
Specification Data:
55972-2808541-6 manufacturers specification
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:

Fiig:

A458a0

Yes - demil/mli